## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of		)
	Toshiki Makimoto, et al.	)
Serial No.:	10/516,380	) Art Unit
Filing Date:	November 30, 2004	) 2818
Confirmation No.:	2860	)
For:	P-TYPE NITRIDE SEMICONDUCTOR STRUCTURE AND BIPOLAR TRANSISTOR	) ) )
Examiner:	Tram Hoang Nguyen	)

## AMENDMENT "A" AND RESPONSE TO OFFICE ACTION OF 27 DEC 2006

Mail Stop: AMENDMENT Commissioner for Patents

PO Box 1450

Alexandria, Virginia 22313-1450

## Examiner:

Applicant submits this paper in response to the Office Action mailed December 27, 2006. Reconsideration is respectfully requested in view of the following remarks:

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Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 5 of this paper.